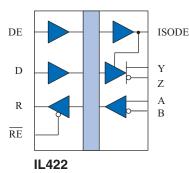


Isolated RS422/RS485 Interface

Functional Diagram



IL422 Receiver				
RE	R	V(A-B)		
Н	Z	Х		
L	Н	\geq 200 mV		
L	L	≤-200 mV		
L	Ι	Open		

IL422 Driver					
DE	D	V(Y-Z)			
L	Х	Z			
Н	Н	≥1.5 V			
Н	L	≤-1.5 V			

H = High Level, L = Low Level I = Indeterminate, X = Irrelevant, Z = High Impedance

Features

- 3.3 V Input Supply Compatible
- 25 ns Maximum Propagation Delay
- 25 Mbps Data Rate
- 1 ns Pulse Skew (typ.)
- ±60 mA Driver Output Capability
- Thermal Shutdown Protection
- Meets or Exceeds ANSI 422-B, EIA 485-A and ITU Recommended V11
- Low EMC Footprint
- -40 °C to +85 °C Operating Temperature
- PROFIBUS Compliant
- 2500 V_{rms} Isolation
- IEC 60747-17 (VDE 0884-17):2021-10 certified; UL 1577 recognized
- 16-pin Wide-Body SOIC Package

Applications

Multi-point or multi-drop transmission on long bus lines in noisy environments.

Description

The IL422 is a galvanically isolated, high-speed differential bus transceiver, designed for bidirectional data communication on balanced transmission lines. The devices use NVE's patented* spintronic Giant Magnetoresistance (GMR) technology. The IL422 was the first isolated RS-422 interface in a standard 16-pin SOIC package to meet the ANSI Standards EIA/TIA-422-B and RS-485.

The IL422 has current limiting and thermal shutdown features to protect against output short circuits and bus contention situations that could cause excessive power dissipation.

Isoloop is a registered trademark of NVE Corporation. *U.S. Patent number 5,831,426; 6,300,617 and others.



Absolute Maximum Ratings⁽¹¹⁾

Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Storage Temperature	Ts	-65		150	°C	
Junction Temperature	T	-65		150	°C	
Voltage Range at A or B Bus Pins		-7		12	V	
Supply Voltage ⁽¹⁾	V_{DD1}, V_{DD2}	-0.5		7	V	
Digital Input Voltage		-0.5		5.5	V	
Digital Output Voltage		-0.5		$V_{DD} + 1$	V	
Continuous Total Power Dissipation				725 377	mW	25°C 85°C
Maximum Output Current	Io			95	mA	
Lead Solder Temperature				260	°C	10 sec.
ESD			2		kV	HBM

Recommended Operating Conditions

Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Supply Voltage	$V_{DD1} V_{DD2}$	3.0 4.5		5.5 5.5	v	
Input Voltage at any Bus Terminal (separately or common mode)	V _I V _{IC}			12 -7	V	
High-Level Digital Input Voltage	V_{IH}	2.4 3.0		V_{DD1}	v	$V_{DD1} = 3.3 V$ $V_{DD1} = 5.0 V$
Low-Level Digital Input Voltage	VIL	0		0.8	V	
Differential Input Voltage ⁽²⁾	V _{ID}			±12	V	
High-Level Output Current (Driver)	Іон			60	mA	
High-Level Digital Output Current (Receiver)	Іон			8	mA	
Low-Level Output Current (Driver)	Iol	-60			mA	
Low-Level Digital Output Current (Receiver)	I _{OL}	-8			mA	
Ambient Operating Temperature	T _A	-40		85	°C	
Junction Temperature	T	-40		100	°C	
Transient Immunity		20			kV/μs	
Digital Input Signal Rise and Fall Times	t _{IR} ,t _{IF}			DC S	table	



IEC 60747-17 (VDE 0884-17):2021-10 (Basic Isolation; VDE File Number 5016933-4880-0001)

- Isolation voltage (VISO): 2500 VRMS
- Transient overvoltage (VIOTM): 4000 VPK
- Surge rating: 4000 V
- Each part tested at 1590 VPK for 1 second, 5 pC partial discharge limit.
- Samples tested at 4000 VPK for 60 sec.; then 1358 VPK for 10 sec. with 5 pC partial discharge limit.

IL422

• Working Voltage (VIORM) 600 VRMS (848 VPK); basic insulation; pollution degree 2

Safety-Limiting Values	Symbol	Value	Units
Safety rating ambient temperature	Ts	180	°C
Safety rating power (180 °C)	Ps	270	mW
Supply current safety rating (total of supplies)	Is	54	mA

UL 1577 (Component Recognition Program File Number E207481)

- 2500 V rating
- Each part tested at 3000 V_{RMS} (4243 V_{PK}) for 1 second
- Each lot sample tested at 2500 V_{RMS} (3536 V_{PK}) for 1 minute

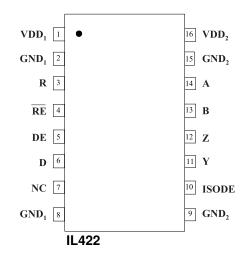
Soldering Profile

Per JEDEC J-STD-020C, MSL-1



IL422 Pin Connections

· · · · · · · · · · · · · · · · · · ·		
1	V _{DD1}	Input Power Supply
2	GND_1	Input Power Supply Ground*
3	R	Output Data from Bus
4	RE	Read Data Enable (if \overline{RE} is high, R = high impedance)
5	DE	Drive Enable
6	D	Data Input to Bus
7	NC	No Internal Connection
8	GND ₁	Input Power Supply Ground*
9	GND ₂	Output Power Supply Ground*
10	ISODE	Isolated DE Output for use in Profibus applications where the state of the isolated drive enable node needs to be monitored
11	Y	Y Bus (Drive – True)
12	Z	Z Bus (Drive – Inverse)
13	В	B Bus (Receive – Inverse)
14	А	A Bus (Receive – True)
15	GND ₂	Output Power Supply Ground*
16	V _{DD2}	Output Power Supply



*NOTE: Pins 2 and 8 are internally connected, as are pins 9 and 15.



Driver Section

Electrical specifications are T_{min} to T_{max} and $V_{DD} = 4.5$ V to 5.5 V unless otherwise stated.

Parameters	Symbol	Min.	Typ. ⁽⁵⁾	Max.	Units	Test Conditions
Input Clamp Voltage	V _{IK}			-1.5	V	$I_{L} = -18 \text{ mA}$
Output voltage	Vo	0		6	V	$I_0 = 0$
Differential Output Voltage ⁽²⁾	V _{OD1}	1.5		6	V	$I_0 = 0$
Differential Output Voltage ⁽²⁾	IV _{OD2} I	1.5	2.5	5	V	$R_L = 54 \Omega$, $V_{DD} = 5 V$
Differential Output Voltage ⁽²⁾⁽⁶⁾	V _{OD3}	1.5		5	V	$R_{\rm L} = 54 \ \Omega, \ V_{\rm DD} = 4.5 \ V$
Change in Magnitude of Differential Output Voltage ⁽⁷⁾	$\Delta V_{\text{OD}} $			±0.2	V	$R_L = 54 \ \Omega \text{ or } 100 \ \Omega$
Common Mode Output Voltage	V _{oc}			3 -1	v	$R_L = 54 \ \Omega \text{ or } 100 \ \Omega$
Change in Magnitude of Common Mode Output Voltage ⁽⁷⁾	$\Delta V_{oc} $			±0.2	v	$R_L = 54 \ \Omega \text{ or } 100 \ \Omega$
Output Current ⁽⁴⁾ Output Disabled	Io			1 -0.8	mA	$V_{O} = 12 V$ $V_{O} = -7 V$
High Level Input Current	I _{IH}			10	μΑ	$V_{I} = 3.5 V$
Low Level Input Current	I_{IL}			-10	μΑ	$V_{I} = 0.4 V$
Short-circuit Output Current	Ios			250 -150 -250	mA	$V_{0} = -6 V$ $V_{0} = 0 V$ $V_{0} = 8 V$
Supply Current $V_{DD1} = +5 V$ $V_{DD1} = +3.3 V$	I_{DD1} I_{DD1}		4 3	6 3	mA	No Load (Outputs Enabled)
	S	Switching Spe	cifications			
Parameters	Symbol	Min.	Typ. ⁽⁵⁾	Max.	Units	Test Conditions
Maximum Data Rate		25			Mbps	$R_{L} = 54 \Omega, C_{L} = 50 pF$
Differential Output Prop Delay	t _D (OD)		16	25	ns	$R_L = 54 \Omega, C_L = 50 pF$
Pulse Skew ⁽¹⁰⁾	$t_s(P)$		1	6	ns	$R_{L} = 54 \Omega, C_{L} = 50 pF$
Differential Output Rise & Fall Time	t _T (OD)		8	10	ns	$R_L = 54 \Omega, C_L = 50 pF$
Output Enable Time to High Level	t _{PZH}		31	65	ns	$R_{L} = 54 \Omega, C_{L} = 50 pF$
Output Enable Time to Low Level	t_{PZL}		22	35	ns	$R_L = 54 \Omega, C_L = 50 pF$
Output Disable Time from High Level	t _{PHZ}		28	50	ns	$R_L = 54 \Omega, C_L = 50 pF$
Output Disable Time from Low Level	t_{PLZ}		16	32	ns	$R_L = 54 \Omega, C_L = 50 pF$
Skew Limit ⁽³⁾	tsk(LIM)		2	8	ns	$R_L = 54 \Omega, C_L = 50 pF$



Receiver Section

Electrical specifications are T_{min} to T_{max} and $V_{DD} = 4.5$ V to 5.5 V unless otherwise stated.

Electrical specifications are T _{min} to T _{max} an Parameters	$\frac{\mathbf{d} \mathbf{v} \mathbf{D} \mathbf{b}}{\mathbf{Symbol}} = 4.5 \mathbf{v} \cdot \mathbf{to} \cdot \mathbf{s}$	Min.	Typ. ⁽⁵⁾	Max.	Units	Test Conditions
Positive-going Input	•		yp.			$V_0 = 2.7 \text{ V},$
Threshold Voltage	V_{IT+}			0.2	V	$I_0 = -0.4 \text{ mA}$
Negative-going Input						$V_0 = 0.5 V,$
Threshold Voltage	V _{IT} -	-0.2			V	$I_0 = 8 \text{ mA}$
Hysteresis Voltage (V _{IT+} – V _{IT-})	V _{HYS}		60		mV	
High Level Digital Output Voltage	Voh	V _{DD} – 0.2			v	$V_{ID} = 200 \text{ mV}$
High Level Digital Output Voltage	V OH	v BB = 0.2			v	$I_{OH} = -20 \ \mu A$
Low Level Digital Output Voltage	Vol			0.2	v	$V_{\rm ID} = -200 \text{ mV}$
						$I_{OH} = 20 \ \mu A$
High-impedance-state output current	I _{oz}			±10	μΑ	$V_0 = 0.4$ to $(V_{DD2}-0.5)$ V
				1		$V_{I} = 12 V$
Line Input Current ⁽⁸⁾	\mathbf{I}_{I}			-0.8	mA	$V_{\rm I} = -7 \text{ V}$
I D I		10	20		1.0	Other Input ^{(11)} = 0 V
Input Resistance	r _I	12	20		kΩ	
Supply Current	I_{DD2}		27	34	mA	No load
	Cuvito	hing Charact	ariatian at F			Outputs Enabled
Parameters	Symbol		Typ. ⁽⁵⁾	v Max.	Units	Test Conditions
Maximum Data Rate	Symbol	Min. 25	1 yp.~/	Max.		
Maximum Data Kate		23			Mbps	$R_{\rm L} = 54 \ \Omega, C_{\rm L} = 50 \ pF$ $V_{\rm O} = -1.5 \ V \ to \ 1.5 \ V,$
Propagation Delay ⁽⁹⁾	t_{PD}		24	32	ns	$V_0 = -1.5 \text{ v to } 1.5 \text{ v},$ $C_L = 15 \text{ pF}$
(10)						$V_0 = -1.5 \text{ V to } 1.5 \text{ V},$
Pulse Skew ⁽¹⁰⁾	tsk(P)		1	6	ns	$C_{\rm L} = 15 \rm pF$
Skew Limit ⁽³⁾	tsk(LIM)		2	8	ns	$R_L = 54 \Omega, C_L = 50 pF$
Output Enable Time To High Level	t _{PZH}		17	24	ns	$C_L = 15 \text{ pF}$
Output Enable Time To Low Level	t_{PZL}		30	45	ns	$C_L = 15 \text{ pF}$
Output Disable Time From High Level	t _{PHZ}		30	45	ns	$C_L = 15 \text{ pF}$
Output Disable Time From Low Level	t_{PLZ}		18	27	ns	$C_L = 15 \text{ pF}$
		hing Characte				
Parameters	Symbol	Min.	Typ. ⁽⁵⁾	Max.	Units	Test Conditions
Maximum Data Rate		25			Mbps	$R_{L} = 54 \Omega, C_{L} = 50 pF$
Propagation Delay ⁽⁹⁾	t _{PD}		27	32	ns	$V_0 = -1.5 V$ to 1.5 V,
Topugation Delay	CI D		27	52	115	$C_L = 15 \text{ pF}$
Pulse Skew ⁽¹⁰⁾	$t_{SK}(P)$		2	6	ns	$V_0 = -1.5 V$ to 1.5 V,
				-		$C_L = 15 \text{ pF}$
Skew Limit ⁽³⁾	t _{sk} (LIM)		4	8	ns	$R_L = 54 \Omega, C_L = 50 pF$
Output Enable Time To High Level	t _{PZH}		20	24	ns	$C_L = 15 \text{ pF}$
Output Enable Time To Low Level	t _{PZL}		33	45	ns	$C_L = 15 \text{ pF}$
Output Disable Time From High Level	t _{PHZ}		33	45	ns	$C_L = 15 \text{ pF}$
Output Disable Time From Low Level	t _{PLZ}		20	27	ns	$C_{L} = 15 \text{ pF}$

Magnetic Field Immunity⁽¹¹⁾

Magnetic Field Immunity at 5 V				
Power Frequency Magnetic Immunity	H_{PF}	3500	A/m	50Hz/60Hz
Pulse Magnetic Field Immunity	H _{PM}	4500	A/m	$t_p = 8\mu s$
Damped Oscillatory Magnetic Field	Hosc	4500	A/m	0.1Hz – 1MHz
Cross-axis Immunity Multiplier ⁽¹²⁾	K _X	2.5		
	Magn	etic Field Immunity at 3.3 V		
Power Frequency Magnetic Immunity	H_{PF}	1500	A/m	50Hz/60Hz
Pulse Magnetic Field Immunity	Hpm	2000	A/m	$t_p = 8\mu s$
Damped Oscillatory Magnetic Field	Hosc	2000	A/m	0.1Hz – 1MHz
Cross-axis Immunity Multiplier ⁽¹²⁾	Kx	2.5		



Insulation Specifications

Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Creepage Distance		8.08				mm
Barrier Impedance			>10 ¹⁴ 7			$\Omega \parallel pF$
Leakage Current			0.2		μΑ	240 V _{RMS} , 60 Hz

Thermal Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Junction-Ambient Thermal Resistance	$\theta_{\rm JA}$		67		°C/W	Double-sided PCB in free air
Junction–Case (Top) Thermal Resistance	$\theta_{\rm JC}$		12			
Junction–Ambient Thermal Resistance	$\theta_{\rm JA}$		46			2s2p PCB in free air per JESD51
Junction–Case (Top) Thermal Resistance	$\theta_{\rm JC}$		9			
Power Dissipation	PD			1500	mW	

Notes:

1. All voltage values are with respect to network ground except differential I/O bus voltages.

- 2. Differential input/output voltage is measured at the noninverting terminal A with respect to the inverting terminal B.
- 3. Skew limit is the maximum propagation delay difference between any two devices at 25°C.
- 4. The power-off measurement in ANSI Standard EIA/TIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.
- 5. All typical values are at V_{DD1} = 3.3 V or 5 V and V_{DD2} = 5 V, and T_A = 25°C.
- 6. The minimum V_{OD2} with a 100 Ω load is either $\frac{1}{2} V_{OD1}$ or 2 V, whichever is greater.
- 7. $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed form one logic state to the other.
- 8. This applies for both power on and power off, refer to ANSI standard RS-485 for exact condition. The EIA/TIA-422-B limit does not apply for a combined driver and receiver terminal.
- 9. Includes 8 ns read enable time. Maximum propagation delay is 25 ns after read assertion.
- 10. Pulse skew is defined as $|t_{PLH} t_{PHL}|$ of each channel.
- 11. The relevant test and measurement methods are given in the Electromagnetic Compatibility section.
- 12. External magnetic field immunity is improved by this factor if the field direction is "end-to-end" rather than to "pin-to-pin."



Application Information

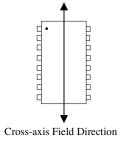
Electrostatic Discharge Sensitivity

This product has been tested for electrostatic sensitivity to the limits stated in the specifications. However, NVE recommends that all integrated circuits be handled with appropriate care to avoid damage. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.

Electromagnetic Compatibility

The IL422 is fully compliant with IEC 61000-6-1 and IEC 61000-6-2 standards for immunity, and IEC 61000-6-3, IEC 61000-6-4, CISPR, and FCC Class A standards for emissions.

Immunity to external magnetic fields is even higher if the field direction is "end-to-end" rather than to "pin-to-pin" as shown in the diagram below:



Dynamic Power Consumption

IsoLoop Isolators achieve their low power consumption from the way they transmit data across the isolation barrier. By detecting the edge transitions of the input logic signal and converting these to narrow current pulses, a magnetic field is created around the GMR Wheatstone bridge. Depending on the direction of the magnetic field, the bridge causes the output comparator to switch following the input logic signal. Since the current pulses are narrow, about 2.5 ns, the power consumption is independent of mark-to-space ratio and solely dependent on frequency. This has obvious advantages over optocouplers, which have power consumption heavily dependent on frequency and time.

The approximate power supply current per channel is:

$$I_{\rm IN} = 40~x~\frac{f}{f_{\rm MAX}}~x~\frac{1}{-4}~mA$$

Where f = operating frequency

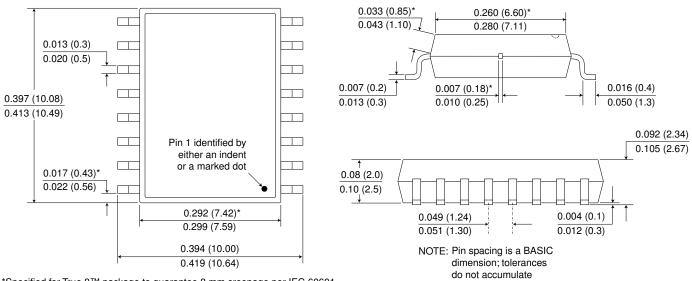
 $f_{MAX} = 50 \text{ MHz}$

Power Supply Decoupling

 V_{DD1} and V_{DD2} should be bypassed with 0.1 μF typical (0.047 μF minimum) capacitors as close as possible to the V_{DD} pins.



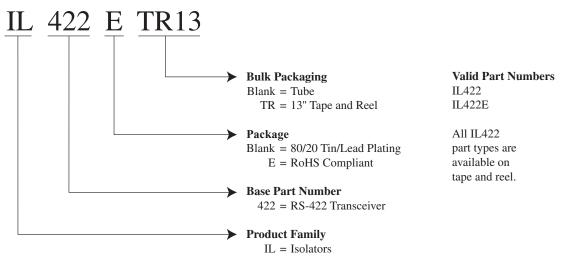
0.3" 16-pin SOIC Package



Dimensions in inches (mm); scale = approx. 5X

*Specified for True 8™ package to guarantee 8 mm creepage per IEC 60601.

Ordering Information and Valid Part Numbers







IL422

ISB-DS-001-IL422-S October 2022	 Changes Upgrade to VDE 0884-17 (p. 3). Updated EMC standards. Deleted <u>minimum</u> magnetic field immunity specifications (p. 6) since it is not 100% tested. Added thermal characteristics (p. 7).
ISB-DS-001-IL422-R	 Change Updated MSL, agency approvals, magnetic immunity, and other specifications.
ISB-DS-001-IL422-Q	 Opdated WSL, agency approvals, magnetic minimumity, and other specifications. Change Update terms and conditions.
ISB-DS-001-IL422-P	 Added clarification of internal ground connections.
ISB-DS-001-IL422-O	ChangeAdded low EMC footprint.
ISB-DS-001-IL422-N	ChangesAdded magnetic field immunity and electromagnetic compatibility specifications.
ISB-DS-001-IL422-M	 Added note on package drawing that pin-spacing tolerances are non-accumulating. Change Changed ordering information to reflect that devices are now fully RoHS compliant with no exemptions.
ISB-DS-001-IL422-L	 Change Reorganized supply current specifications; misc. minor changes
ISB-DS-001-IL422-K	ChangeEliminated soldering profile chart
ISB-DS-001-IL422-J	ChangeUpdated open input state in truth table
ISB-DS-001-IL422-I	ChangeUpdated package drawing; misc.
ISB-DS-001-IL422-H	ChangeUpdated UL and IEC approvals
ISB-DS-001-IL422-G	 Changes Revision letter added. Ordering Information Removed. IEC 61010-1 Classification: "Reinforced Insulation" added. Notes added. IR Soldering Profile added Ordering Information added.

10



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ISB-DS-001-IL422-S

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